



**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant: Li Docket No.: 2003 P 54557 US  
Serial No.: 10/771,075 Art Unit: 2811  
Filed: February 3, 2004 Examiner: Gene M. Munson  
For: Transistor with Doped Gate Dielectric

**Certificate of Mailing via First Class Mail (37 C.F.R. § 1.8(a))**

Date of Deposit: April 21, 2005

I hereby certify that the below listed correspondence is being deposited with the United States Postal Service on the date indicated above as first class mail in an envelope addressed to: Mail Stop Amendment, Commissioner for Patents, P. O. Box 1450, Alexandria, VA 22313-1450.

Certificate of Mailing via First Class Mail (1 page)  
Amendment (8 pages)  
Information Disclosure Statement (1 original & 1 copy)  
IDS Form PTO/SB/08A with ten (10) references cited (1 page)  
Copy of PCT International Search Report (4 pages)  
Return Postcard

Respectfully submitted,

A handwritten signature in black ink, appearing to read "Carrie Roth".

Carrie Roth  
Legal Assistant

Slater & Matsil, L.L.P.  
17950 Preston Rd., Suite 1000  
Dallas, TX 75252  
Tel: 972-732-1001  
Fax: 972-732-9218